BLP9H10S-350A

Power LDMOS transistor

Rev. 1 — 6 July 2021

AMPLEON

Product data sheet

1. Product profile

1.1 General description

350 W LDMOS packaged asymmetric Doherty power transistor for base station applications at frequencies from 600 MHz to 960 MHz.

Table 1. Typical performance

Typical RF performance at T_{case} = 25 °C in an asymmetrical Doherty circuit; V_{DS} = 48 V; I_{Dq} = 400 mA (main); $V_{GS(amp)peak}$ = 0.5 V, unless otherwise specified.

Test signal	f	V_{DS}	$P_{L(AV)}$	G_p	η_D	ACPR
	(MHz)	(V)	(dBm)	(dB)	(%)	(dBc)
1-carrier W-CDMA	617 to 652	48	47.5	19	53.4	–34.9 [1]
	859 to 894	48	47.7	18.5	53	–33.3 [1]

[1] Test signal: 1-carrier W-CDMA; 3GPP test model 1; 64 DPCH; PAR = 9.9 dB at 0.01 % probability on CCDF.

1.2 Features and benefits

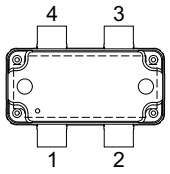
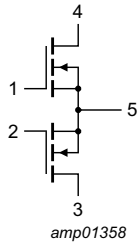
- Excellent ruggedness
- High efficiency
- Low thermal resistance providing excellent thermal stability
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent digital pre-distortion capability
- Internal integrated wideband input for ease of use
- Integrated double sided ESD protection
- For RoHS compliance see the product details on the Ampleon website

1.3 Applications

- RF power amplifiers for base stations and multi carrier applications in the 600 MHz to 960 MHz frequency range

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	gate1		
2	gate2		
3	drain2		
4	drain1		
5	source [1]		

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BLP9H10S-350A	-	overmolded plastic earless flanged package; 4 leads	OMP-780-4F-1

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	105	V
$V_{GS(amp)main}$	main amplifier gate-source voltage		–6	+11	V
$V_{GS(amp)peak}$	peak amplifier gate-source voltage		–6	+11	V
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature	[1]	-	200	°C
T_{case}	case temperature	operating [1]	–40	+125	°C

[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	V_{DS} = 48 V; I_{Dq} = 400 mA (main); $V_{GS(amp)peak}$ = 0.5 V; T_{case} = 80 °C		
		P_L = 59 W	0.66	K/W
		P_L = 74 W	0.6	K/W

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6. Characteristics

Table 6. DC characteristics

T_j = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Main device						
$V_{(BR)DSS}$	drain-source breakdown voltage	V_{GS} = 0 V; I_D = 1 mA	108	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V_{DS} = 10 V; I_D = 100 mA	1.5	1.9	2.5	V
V_{GSq}	gate-source quiescent voltage	V_{DS} = 48 V; I_D = 400 mA	1.45	2.0	2.45	V
I_{DSS}	drain leakage current	V_{GS} = 0 V; V_{DS} = 50 V	-	-	1.4	µA
I_{DSX}	drain cut-off current	V_{GS} = $V_{GS(th)}$ + 3.75 V; V_{DS} = 10 V	-	16.8	-	A
I_{GSS}	gate leakage current	V_{GS} = 11 V; V_{DS} = 0 V	-	-	140	nA
g_{fs}	forward transconductance	V_{DS} = 10 V; I_D = 5 A	-	7.0	-	S
$R_{DS(on)}$	drain-source on-state resistance	V_{GS} = $V_{GS(th)}$ + 3.75 V; I_D = 3.5 A	-	220	370	mΩ
Peak device						
$V_{(BR)DSS}$	drain-source breakdown voltage	V_{GS} = 0 V; I_D = 1.5 mA	108	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V_{DS} = 10 V; I_D = 150 mA	1.5	2.0	2.5	V
V_{GSq}	gate-source quiescent voltage	V_{DS} = 48 V; I_D = 600 mA	1.7	2.2	2.7	V
I_{DSS}	drain leakage current	V_{GS} = 0 V; V_{DS} = 50 V	-	-	1.4	µA
I_{DSX}	drain cut-off current	V_{GS} = $V_{GS(th)}$ + 3.75 V; V_{DS} = 10 V	-	24.5	-	A
I_{GSS}	gate leakage current	V_{GS} = 11 V; V_{DS} = 0 V	-	-	140	nA
g_{fs}	forward transconductance	V_{DS} = 10 V; I_D = 7.5 A	-	10.3	-	S
$R_{DS(on)}$	drain-source on-state resistance	V_{GS} = $V_{GS(th)}$ + 3.75 V; I_D = 5.25 A	-	151	250	mΩ

Table 7. RF characteristics

Test signal: 1-carrier W-CDMA; PAR = 9.6 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 1 - 64 DPCH; f_1 = 619.5 MHz; f_2 = 649.5 MHz; RF performance at V_{DS} = 48 V; I_{Dq} = 400 mA (main); $V_{GS(amp)peak}$ = 0.5 V; T_{case} = 25 °C; unless otherwise specified; in an asymmetrical Doherty production test circuit at frequencies from 617 MHz to 652 MHz.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
G_p	power gain	$P_{L(AV)}$ = 56.2 W	16.7	18.6	-	dB
RL_{in}	input return loss	$P_{L(AV)}$ = 56.2 W	-	–15	–9	dB
η_D	drain efficiency	$P_{L(AV)}$ = 56.2 W	46	52	-	%
ACPR	adjacent channel power ratio	$P_{L(AV)}$ = 56.2 W	-	–33	–29	dBc

Table 8. RF characteristics

Test signal: 1-carrier W-CDMA; PAR = 9.6 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 1 - 64 DPCH; f_1 = 619.5 MHz; f_2 = 649.5 MHz; RF performance at V_{DS} = 48 V; I_{Dq} = 400 mA (main); $V_{GS(amp)peak}$ = 0.5 V; T_{case} = 25 °C; unless otherwise specified; in an asymmetrical Doherty production test circuit at frequencies from 617 MHz to 652 MHz.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
PAR_O	output peak-to-average ratio	$P_{L(AV)}$ = 110 W	5.6	6.3	-	dB
$P_{L(M)}$	peak output power	$P_{L(AV)}$ = 110 W	391	465	-	W

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7. Test information

7.1 Ruggedness in Doherty operation

The BLP9H10S-350A is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 52 V; I_{Dq} = 400 mA; $V_{GS(amp)peak}$ = 0.50 V; f = 634 MHz; P_L = 140 W (5 dB OBO); pulsed CW (t_p = 100 μs; δ = 10%).

7.2 Impedance information

Table 9. Typical impedance of main device

Measured load-pull data of main device; I_{Dq} = 400 mA (main); V_{DS} = 48 V; pulsed CW (t_p = 100 μs; δ = 10 %).

f	Z_S [1]	Z_L [1]	P_L [2]	η_D [2]	G_p [2]
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)
Maximum power load					
600	7.9 – j3.22	2.6 + j0.4	217.8	62.6	17.8
617	7.5 – j2.85	2.6 + j0.4	231.3	67.6	18.3
635	6.9 – j2.50	2.6 + j0.4	224.2	66.8	18.6
652	6.4 – j2.81	2.5 + j0.4	197.3	61.5	17.9
698	5.5 – j3.05	2.0 + j0.3	225.8	64.4	18.7
720	5.2 – j3.45	2.0 + j0.3	229.0	66.2	19.0
746	5.0 – j4.15	2.6 – j0.3	224.2	62.0	18.4
769	4.9 – j4.72	2.6 – j0.3	224.9	63.2	18.5
805	4.9 – j5.54	2.6 – j0.3	220.0	62.8	18.4
820	4.9 – j5.93	2.1 + j0.0	223.9	65.1	18.5
869	5.6 – j7.48	2.1 + j0.0	217.7	66.4	18.5
880	5.7 – j7.87	2.1 + j0.0	214.6	66.1	18.6
894	6.2 – j8.35	2.8 – j0.9	211.9	58.3	17.6
915	6.7 – j8.98	2.1 + j0.0	214.9	67.9	18.5
925	7.1 – j9.30	2.0 – j0.7	217.1	59.5	17.3
942	7.8 – j9.84	2.0 – j0.8	218.6	60.9	17.2
960	8.7 – j10.40	2.0 – j0.7	217.1	61.4	17.2
Maximum drain efficiency load					
600	7.4 – j2.79	2.3 + j2.7	136.4	71.5	20.1
617	6.5 – j2.41	1.7 + j3.1	104.4	78.5	21.1
635	6.3 – j2.44	2.3 + j2.7	131.6	76.5	20.9
652	6.1 – j2.81	2.2 + j2.7	119.2	70.7	20.0
698	5.0 – j3.10	1.8 + j2.2	130.9	74.3	21.2
720	4.7 – j3.56	1.8 + j2.2	128.4	76.0	21.5
746	4.7 – j4.13	2.2 + j1.7	159.6	73.9	20.8
769	4.6 – j4.73	2.2 + j1.7	154.7	74.1	20.8
805	4.6 – j5.48	1.7 + j1.4	147.8	72.2	20.5
820	4.7 – j5.94	1.8 + j1.4	155.8	74.8	20.5

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Table 9. Typical impedance of main device *...continued*

Measured load-pull data of main device; I_{Dq} = 400 mA (main); V_{DS} = 48 V; pulsed CW (t_p = 100 μs; δ = 10 %).

f	Z_S [1]	Z_L [1]	P_L [2]	η_D [2]	G_p [2]
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)
869	5.4 – j7.51	1.8 + j1.4	142.1	73.0	20.5
880	5.6 – j7.91	1.8 + j1.4	139.6	72.6	20.6
894	6.0 – j8.37	1.8 + j1.4	134.6	71.9	20.6
915	6.6 – j8.98	1.8 + j1.4	137.5	73.6	20.4
925	6.9 – j9.28	2.0 + j0.7	177.7	73.9	19.6
942	7.6 – j9.85	1.2 + j1.2	112.6	74.0	20.4
960	8.6 – j10.36	1.2 + j1.2	107.5	73.2	20.4

[1] Z_S and Z_L defined in Figure 1.

[2] At 3 dB gain compression.

Table 10. Typical impedance of peak device

Measured load-pull data of peak device; I_{Dq} = 600 mA (peak); V_{DS} = 48 V; pulsed CW (t_p = 100 μs; δ = 10 %).

f	Z_S [1]	Z_L [1]	P_L [2]	η_D [2]	G_p [2]
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)
Maximum power load					
600	5.4 – j1.98	1.9 – j0.1	315.65	65.7	18.3
617	5.0 – j1.95	1.9 + j0.0	333.29	71.48	18.7
635	4.5 – j1.93	1.8 – j0.7	316.23	60.01	18.0
652	4.3 – j2.43	1.7 – j0.7	268.92	52.85	16.8
680	3.8 – j2.61	1.8 – j0.7	316.88	60.66	18.2
698	3.7 – j2.86	1.8 – j0.7	326.76	62.1	18.4
720	3.5 – j3.22	1.8 – j0.8	333.94	63.94	18.6
746	3.4 – j3.71	1.8 – j0.7	326.84	64.01	18.6
757	3.4 – j3.92	1.8 – j0.7	326.03	63.97	18.6
769	3.4 – j4.13	1.8 – j0.7	323.31	64.53	18.6
790	3.5 – j4.54	1.8 – j0.7	325.31	66.62	18.8
800	3.6 – j4.73	1.8 – j0.7	314.55	64.83	18.6
805	3.6 – j4.81	1.8 – j0.7	318.3	66.2	18.7
820	3.7 – j5.12	1.8 – j0.7	315.5	65.8	18.3
869	4.5 – j6.02	1.6 – j1.4	300.5	56.2	17.1
880	4.6 – j6.20	1.8 – j0.7	303.4	66.7	18.6
894	5.0 – j6.46	1.6 – j1.4	302.2	56.9	17.3
894	5.2 – j6.57	1.6 – j1.4	299.4	56.9	17.2
915	5.6 – j6.72	1.6 – j1.4	302.4	58.0	17.2
925	5.8 – j6.81	1.6 – j1.4	305.8	58.9	17.4
942	6.5 – j6.91	1.6 – j1.4	308.6	60.1	17.5
950	6.8 – j6.93	1.6 – j1.4	308.6	60.6	17.6
960	7.2 – j6.86	1.6 – j1.4	306.8	61.4	17.7

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Table 10. Typical impedance of peak device *...continued*

Measured load-pull data of peak device; I_{Dq} = 600 mA (peak); V_{DS} = 48 V; pulsed CW (t_p = 100 μs; δ = 10 %).

f	Z_S [1]	Z_L [1]	P_L [2]	η_D [2]	G_p [2]
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)
Maximum drain efficiency load					
600	5.1 – j1.79	1.6 + j1.3	213.4	72.1	20.1
617	4.7 – j1.81	1.6 + j1.3	210.7	79.3	20.6
635	4.1 – j1.85	1.6 + j1.3	197.0	76.8	21.2
652	4.2 – j2.28	1.5 + j1.3	170.5	67.5	19.6
680	3.6 – j2.63	1.6 + j1.4	182.5	74.4	21.2
698	3.5 – j2.81	1.8 + j0.7	252.8	74.6	20.6
720	3.2 – j3.13	1.1 + j1.0	172.4	76.4	21.5
746	3.2 – j3.60	1.3 + j0.5	232.1	74.5	20.6
757	3.2 – j3.82	1.3 + j0.5	229.8	74.8	20.7
769	3.3 – j4.05	1.3 + j0.5	220.9	74.0	20.7
790	3.3 – j4.46	1.3 + j0.5	210.7	76.4	21.0
800	3.4 – j4.65	1.3 + j0.5	200.5	72.2	20.7
805	3.4 – j4.73	1.3 + j0.5	200.4	74.6	20.9
820	3.6 – j5.04	1.3 + j0.5	194.2	73.1	20.5
869	4.27 – j5.87	1.26 – j0.06	233.59	70.62	19.68
880	4.50 – j6.11	1.27 – j0.06	237.96	71.25	19.78
894	4.82 – j6.33	1.26 – j0.06	230.09	71.17	19.99
894	5.04 – j6.43	1.26 – j0.06	222.33	69.87	19.83
915	5.40 – j6.54	1.26 – j0.06	222.83	71.2	19.9
925	5.69 – j6.61	1.26 – j0.05	215.03	71.88	20.15
942	6.30 – j6.66	1.26 – j0.06	210.6	72.56	20.29
950	6.57 – j6.65	1.26 – j0.06	205.08	71.78	20.35
960	6.98 – j6.51	1.26 – j0.06	197.23	71.54	20.45

[1] Z_S and Z_L defined in Figure 1.

[2] At 3 dB gain compression.

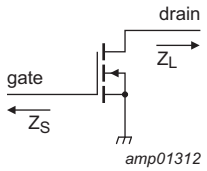
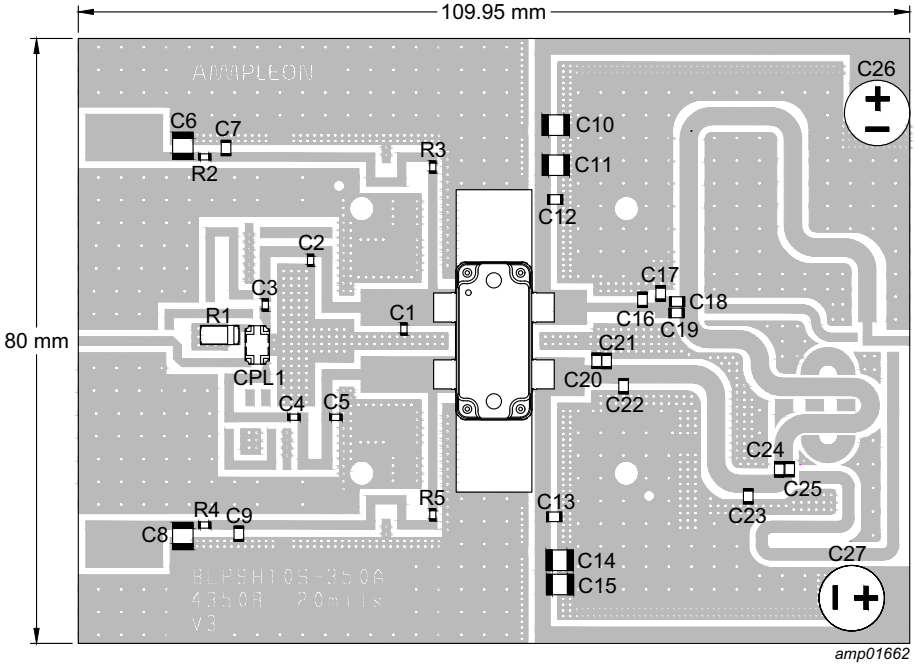


Fig 1. Definition of transistor impedance

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7.3 Test circuit



Printed-Circuit Board (PCB): Rogers 4350B: ε_r = 3.66; thickness = 0.508 mm; thickness copper plating = 35 μm. See Table 11 for a list of components.

Fig 2. Component layout

Table 11. List of components

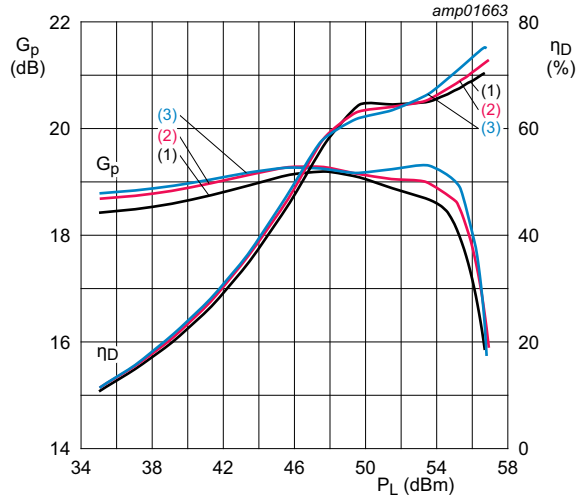
See Figure 2 for component layout.

Component	Description	Value	Remarks
C1	multilayer ceramic chip capacitor	3.6 pF	Murata: GQM21 series
C2, C5, C24, C25	multilayer ceramic chip capacitor	10 pF	Murata: GQM21 series
C3	multilayer ceramic chip capacitor	20 pF	Murata: GQM21 series
C4	multilayer ceramic chip capacitor	47 pF	Murata: GQM21 series
C6, C8, C10, C11, C14, C15	multilayer ceramic chip capacitor	4.7 μF, 100 V	Murata: GRM31CC72A475KE11L
C7, C9, C12, C13	multilayer ceramic chip capacitor	100 pF	Murata: GQM21 series
C16	multilayer ceramic chip capacitor	8.2 pF	Murata: GQM21 series
C17	multilayer ceramic chip capacitor	9.1 pF	Murata: GQM21 series
C18, C19	multilayer ceramic chip capacitor	22 pF	Murata: GQM21 series
C20, C21, C22	multilayer ceramic chip capacitor	12 pF	Murata: GQM21 series
C23	multilayer ceramic chip capacitor	2.0 pF	Murata: GQM21 series
C26, C27	electrolytic capacitor	470 μF, 100 V	
R1	SMD resistor	50 Ω, 16 W	Anaren: C16A50Z4
R2, R3, R4, R5	SMD resistor	5.1 Ω, 1 %	0603
CPL1	hybrid coupler	2 dB, 90°	Anaren: X3C06F1-02S

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7.4 Graphical data

7.4.1 Pulsed CW



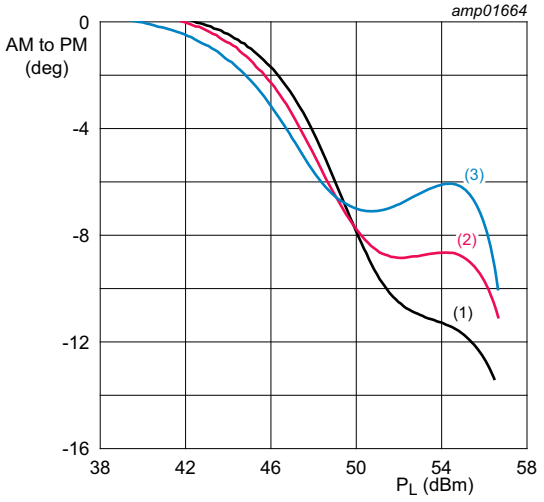
V_{DS} = 48 V; I_{Dq} = 400 mA; $V_{GS(amp)peak}$ = 0.5 V; t_p = 100 µs; δ = 10 %.

(1) f = 617 MHz

(2) f = 634 MHz

(3) f = 652 MHz

Fig 3. Power gain and drain efficiency as function of output power; typical values



V_{DS} = 48 V; I_{Dq} = 400 mA; $V_{GS(amp)peak}$ = 0.5 V; t_p = 100 µs; δ = 10 %.

(1) f = 617 MHz

(2) f = 634 MHz

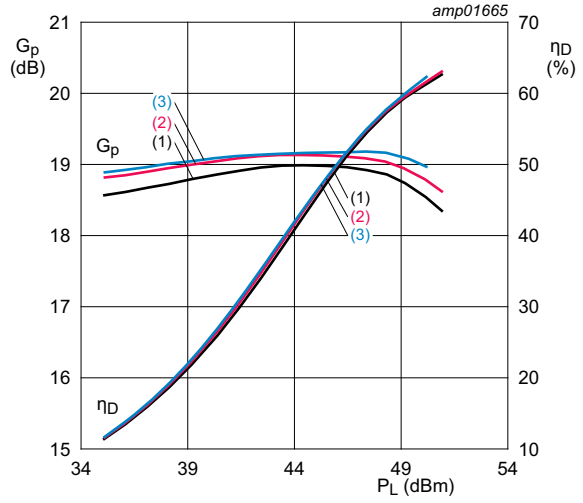
(3) f = 652 MHz

Fig 4. Normalized AM to PM as a function of output power; typical values

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7.4.2 1-Carrier W-CDMA

PAR = 9.9 dB per carrier at 0.01 % probability on CCDF; 3GPP test model 1 with 64 DPCH (100 % clipping).



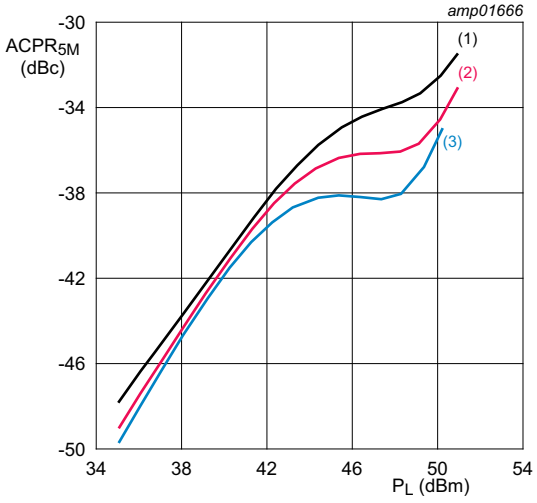
V_{DS} = 48 V; I_{Dq} = 400 mA; $V_{GS(amp)peak}$ = 0.5 V.

(1) f = 617 MHz

(2) f = 634 MHz

(3) f = 652 MHz

Fig 5. Power gain and drain efficiency as function of output power; typical values



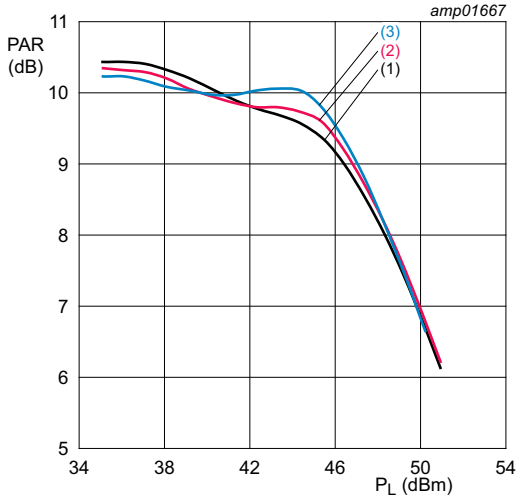
V_{DS} = 48 V; I_{Dq} = 400 mA; $V_{GS(amp)peak}$ = 0.5 V.

(1) f = 617 MHz

(2) f = 634 MHz

(3) f = 652 MHz

Fig 6. Adjacent channel power ratio (5 MHz) as a function of output power; typical values



V_{DS} = 48 V; I_{Dq} = 400 mA; $V_{GS(amp)peak}$ = 0.5 V.

(1) f = 617 MHz

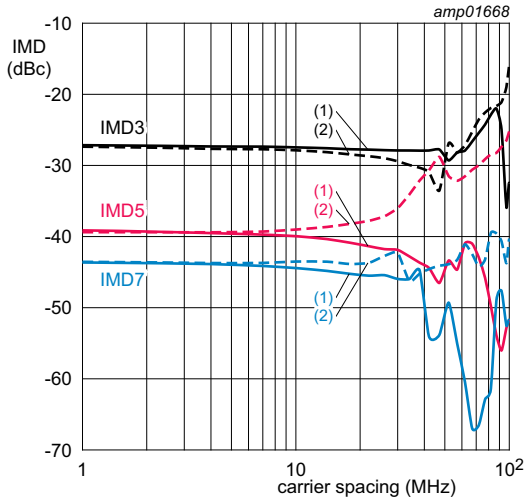
(2) f = 634 MHz

(3) f = 652 MHz

Fig 7. Peak-to-average power ratio as a function of output power; typical values

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7.4.3 2-Tone VBW



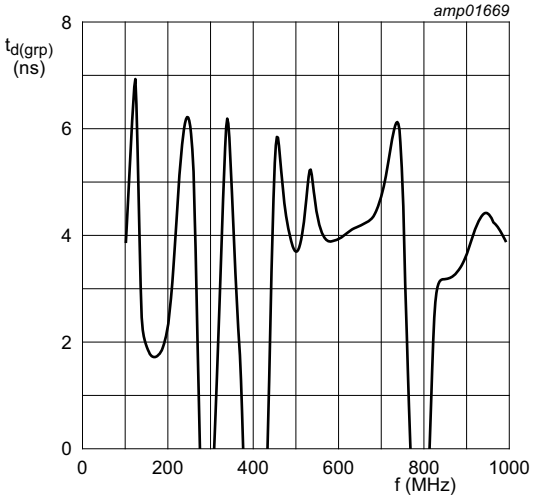
V_{DS} = 48 V; I_{Dq} = 400 mA; $V_{GS(amp)peak}$ = 0.5 V; f_c = 634 MHz.

(1) IMD low

(2) IMD high

Fig 8. VBW capability in Doherty demo board

7.4.4 Group delay



V_{DS} = 48 V; I_{Dq} = 820 mA; $V_{GS(amp)peak}$ = 0.25 V.

Fig 9. Group delay time as a function of frequency; typical values

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8. Package outline

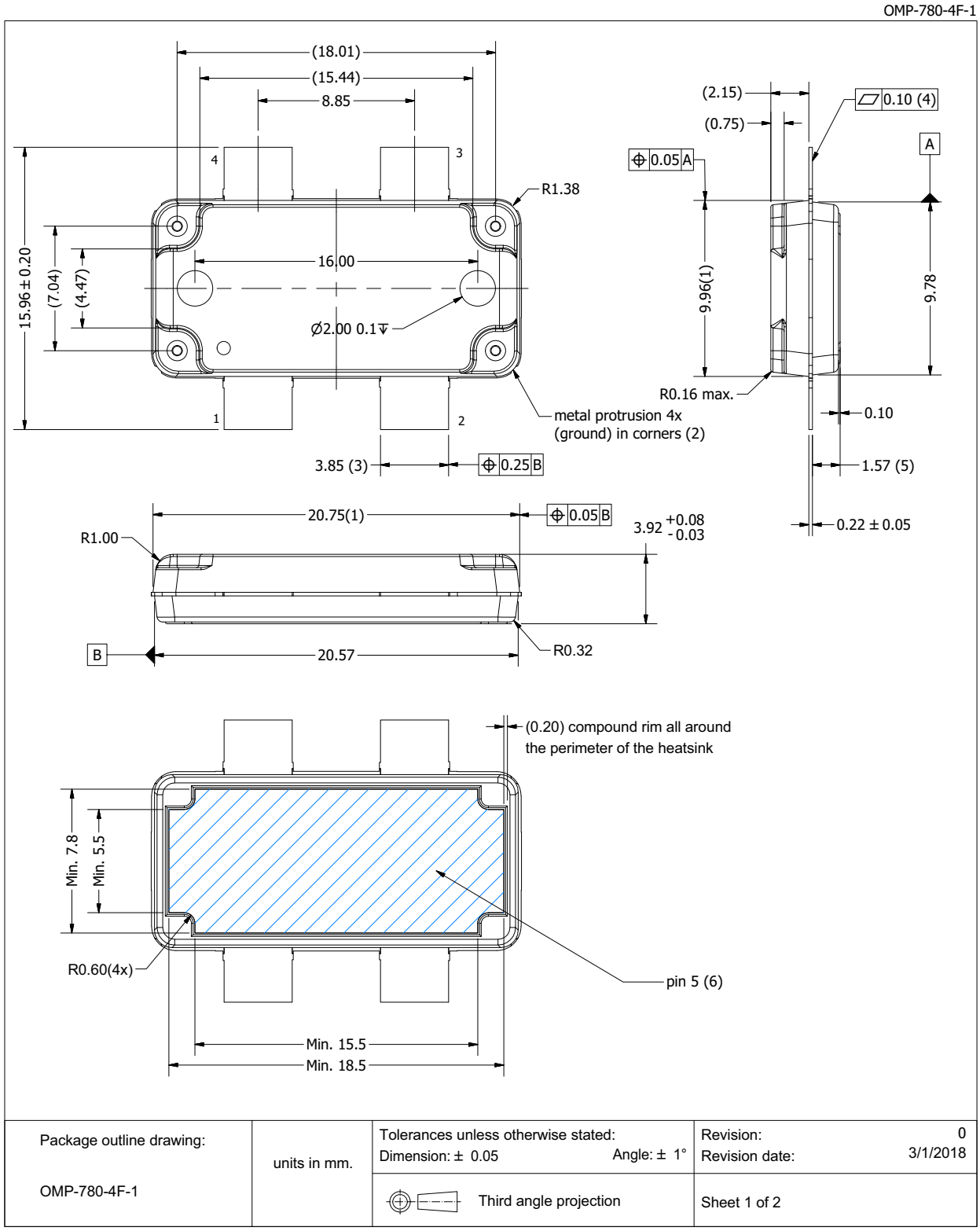
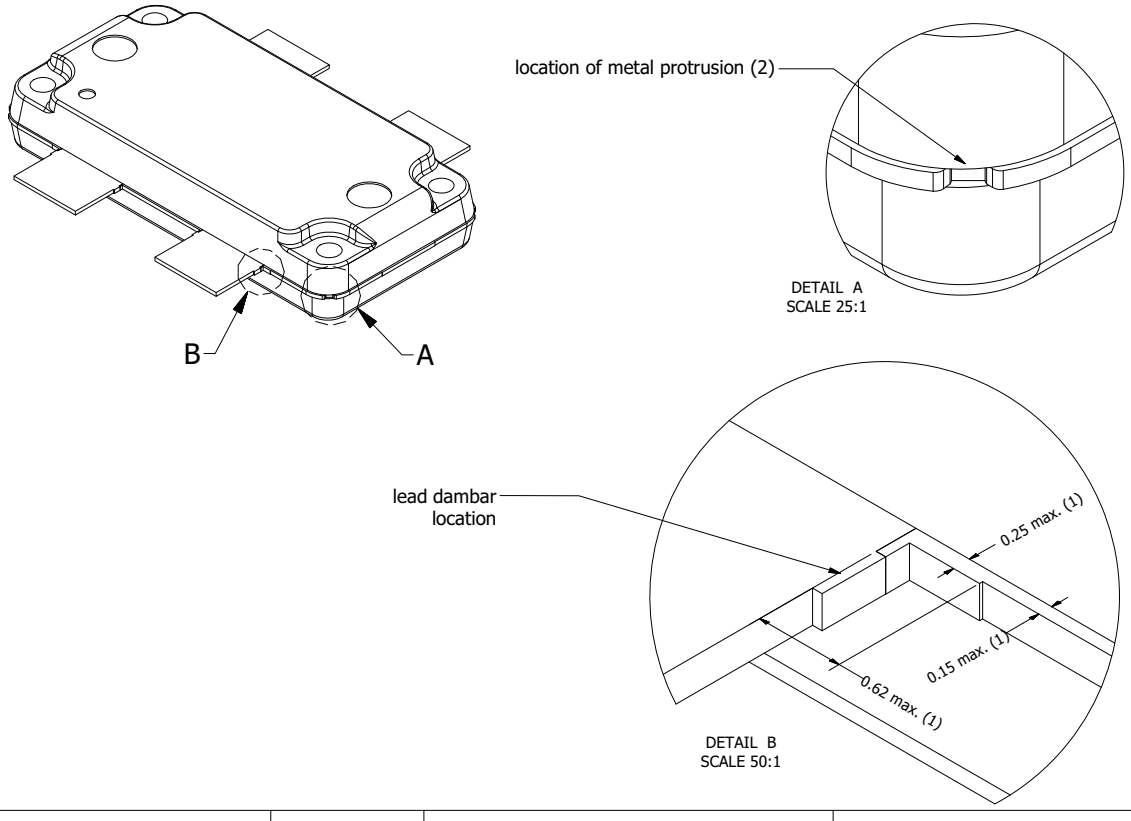


Fig 10. Package outline OMP-780-4F-1 (sheet 1 of 2)

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OMP-780-4F-1

Drawing Notes	
Items	Description
(1)	Dimensions are excluding mold protrusion. All areas located adjacent to the leads have a maximum mold protrusion of 0.25 mm (per side) and max. 0.62 mm in length. At all other areas the mold protrusion is maximum 0.15 mm per side. See also detail B.
(2)	The metal protrusion (tie bars) in the corner will not stick out of the molding compound protrusions (detail A).
(3)	The lead dambar (metal) protrusions are not included. Add 0.14 mm max to the total lead dimension at the dambar location.
(4)	The lead coplanarity over all leads is 0.1 mm maximum.
(5)	Dimension is measured 0.5 mm from the edge of the top package body.
(6)	The hatched area indicates the exposed metal heatsink.
(7)	The leads and exposed heatsink are plated with matte Tin (Sn).



Package outline drawing: OMP-780-4F-1	units in mm.	Tolerances unless otherwise stated: Dimension: ± 0.05 Angle: ± 1° Third angle projection	Revision: 0 Revision date: 3/1/2018 Sheet 2 of 2

Fig 11. Package outline OMP-780-4F-1 (sheet 2 of 2)

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9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

Table 12. ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C3 [1]
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	2 [2]

[1] CDM classification C3 is granted to any part that passes after exposure to an ESD pulse of 1000 V.

[2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V.

10. Abbreviations

Table 13. Abbreviations

Acronym	Description
3GPP	3rd Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MTF	Median Time to Failure
PAR	Peak-to-Average Ratio
RoHS	Restriction of Hazardous Substances
SMD	Surface Mounted Device
VBW	Video Bandwidth
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

11. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLP9H10S-350A v.1	20210706	Product data sheet	-	-

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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